

Analog Clock IC with Melody

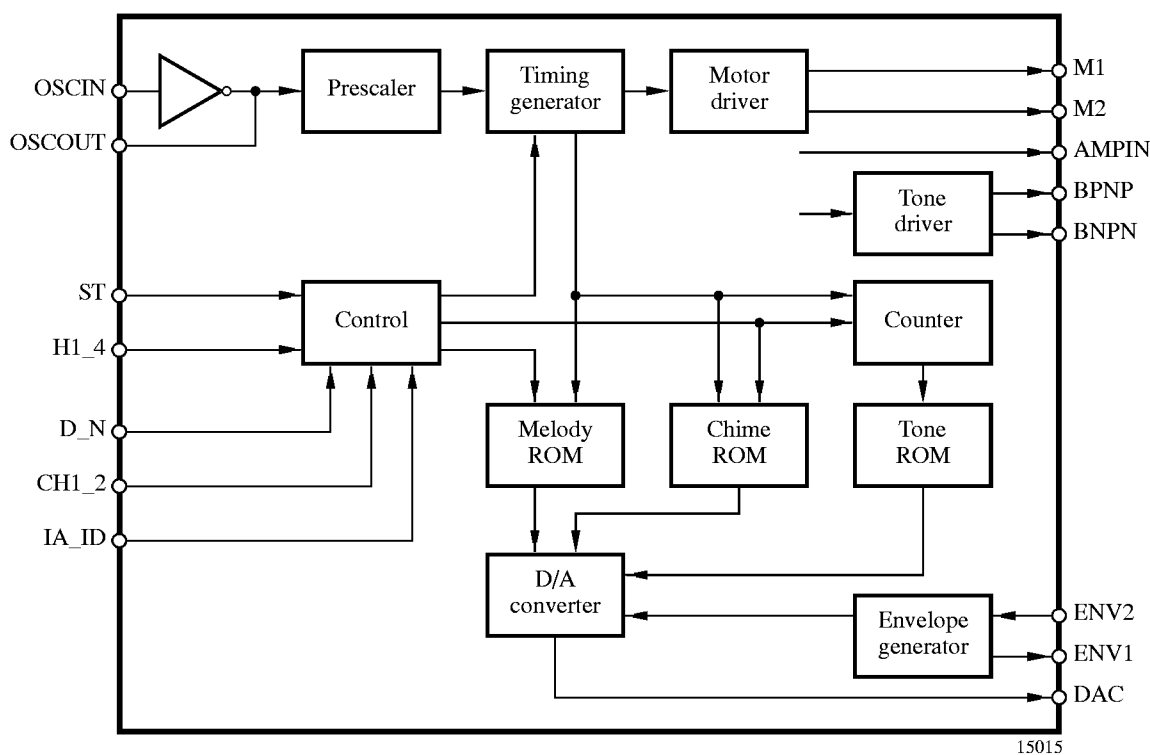
Description

The e5310 is an integrated circuit in low-power CMOS technology for analog timers with high-quality melody and hourly chime output.

Features

- Digital synthesizer for high-quality melody sound
- Mask-programmable melody ROM
- Two sequences with 64 notes each or one sequence with 128 notes
- Hourly chime
- Quarter or half hour melody mode
- Day/ night sound attenuation
- Melody on/ off capability
- 4.192-MHz on-chip quartz oscillator
- Motor pulse output with a pulse length of 47 ms (31 ms available as option)

Block Diagram



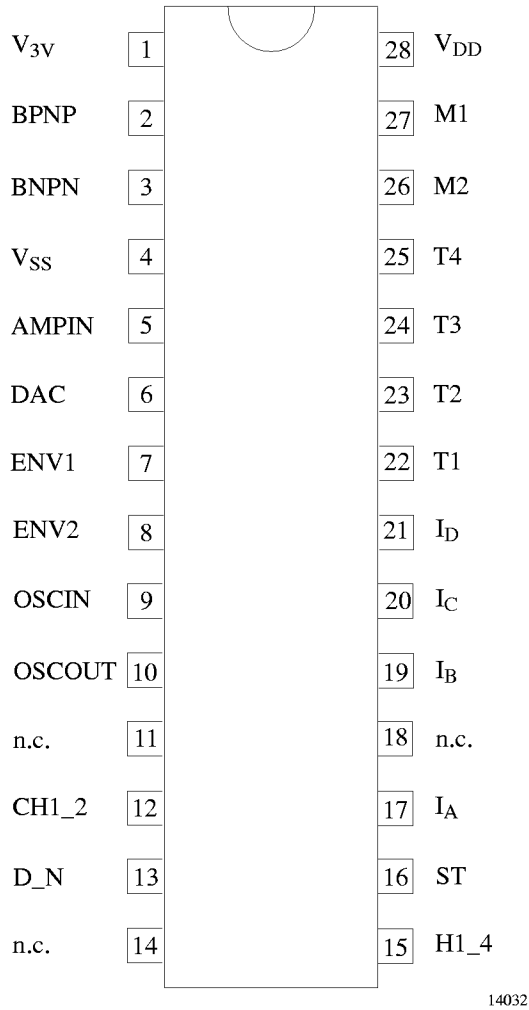


Figure 1. Pinning e5310

Pin	Symbol	Function
1	V _{3V}	
2	BNPN *)	
3	BNPN	
4	V _{SS}	
5	AMPIN *)	
6	DAC	
7	ENV1	
8	ENV2	
9	OSCIN	
10	OSCOUT	
11	n.c.	
12	CH1_2	
13	D_N	
14	n.c.	
15	H1_4	
16	ST	
17	I _A	
18	n.c.	
19	I _B	
20	I _C	
21	I _D	
22	T1	
23	T2	
24	T3	
25	T4	
26	M2	
27	M1	
28	V _{DD}	

*) These pins are not available for type e5310A

Absolute Maximum Ratings

Parameters	Symbol	Value	Unit
Supply voltage 1	V _{DD}	-0.3 to +2.0 V	V
Supply voltage 2	V _{3V}	-0.3 to +4.0 V	V
Input voltage range (on any pins)	V _{IN}	$(V_{SS} - 0.3 \text{ V}) \leq V_{IN} \leq (V_{DD} + 0.3 \text{ V})$	V
Output voltage	V _{OUT}	$(V_{SS} - 0.3 \text{ V}) \leq V_{OUT} \leq (V_{DD} + 0.3 \text{ V})$	V
Output current	I _{OUT}	30	mA
Power dissipation (DIL package)	P _{tot}	125 mW	mW
Operating ambient temperature range	T _{amb}	-10 to +60	°C
Storage temperature range	T _{stg}	-40 to +125	°C
Soldering temperature (t < 10 s)	T _{sd}	260	°C

Absolute maximum ratings define parameter limits which, if exceeded, may permanently change or damage the device. All inputs and outputs in this circuit are protected against electrostatic discharges. However,

precautions to minimize the build-up of electrostatic charges during handling are recommended. This circuit is protected against supply voltage reversal for typically 5 minutes.

Operating Characteristics

$V_{DD} = 1.5\text{ V}$, $V_{SS} = 0\text{ V}$, $T_{amb} = +25^\circ\text{C}$; unless otherwise specified. All voltage levels are measured with reference to V_{SS} . The current flowing into the device is positive.

Parameters	Test Conditions / Pins	Symbol	Min.	Typ.	Max.	Unit
Supply voltage 1		V_{DD}	1.2	1.5	1.8	V
Supply voltage 2		V_{3V}	2.4	3.0	3.6	V
Operating current	Note 1	I_{DD}		60	110	μA
Motor outputs M1 and M2						
Output current	$R_L = 200\ \Omega$, $V_{DD} = 1.2\text{ V}$	I_M	3.5	4		mA
Motor period		t_M		1		s
Pulse width *) Mask option		t_{PW}	31.2 *)	46.8		ms
Hour code input pins I_A, I_B, I_C and I_D						
Input current high	$V_{IN} = V_{DD}$	I_{IH}		4	15	μA
Control input pins D_N and $CH1_2$						
Input current high	$V_{IN} = V_{DD}$	I_{IH}		1	4	μA
Input current low	$V_{IN} = V_{SS}$	I_{IL}		-1	-4	μA
Quartz oscillator						
Frequency		f_C		4.194		MHz
Start-up time	$V_{DD} = 1.2\text{ V}$	t_{Start}		2	3	s
Frequency stability	$\Delta V_{DD} = 100\text{ mV}$	$\Delta f/f$		0.2	0.6	ppm
e5310A Note 2						
Output current	$BNPN = V_{SS}$	I_{BNPN}	0.2		0.5	mA
e5310B Note 2						
Output current	$BNPN = V_{SS}$, $AMPIN = V_{SS}$	I_{BNPN}	0.25			mA
Output current	$BPNP = V_{DD}$, $AMPIN = V_{DD}$	I_{BPNP}	-0.3			mA
Output current	$DAC = V_{DD}$	I_{DAC}	13		28	μA
e5310C with $V_{3V} = 3\text{ V}$ Note 2						
Output current	$BNPN = V_{SS}$, $AMPIN = V_{SS}$	I_{BNPN}	2.0			mA
Output current	$BPNP = 3\text{ V}$, $AMPIN = 3\text{ V}$	I_{BPNP}	2.5			mA
Output current	$DAC = V_{DD}$	I_{DAC}	13		28	μA

Note 1: This current is measured when the crystal oscillator is active, not in melody mode and no motor load

Note 2: Output current measured with $R_{ENV2} = 560\text{ k}\Omega$ and all tone ROM output bits = 1

Table 2. Truth Table for Hourly Chime

I_D	I_C	I_B	I_A	Hour	Chimes
0	0	0	1	1:00	1
0	0	1	0	2:00	2
0	0	1	1	3:00	3
0	1	0	0	4:00	4
0	1	0	1	5:00	5
0	1	1	0	6:00	6
0	1	1	1	7:00	7
1	0	0	0	8:00	8
1	0	0	1	9:00	9
1	0	1	0	10:00	10
1	0	1	1	11:00	11
1	1	0	0	12:00	12

Application Circuit Diagrams Using the e5310

Function select according to switch position:

CH1_2	=	VSS	Melody off
CH1_2	=	VDD	Melody 1 (Westminster)
CH1_2	=	open	Melody 2 (Bim-bam)
D_N	=	VSS	No sound during night time
D_N	=	VDD	Half volume level at night
D_N	=	open	Same volume level for day and night
H1_4	=	VDD	Chime on full hour only
H1_4	=	VSS or open	1/4, 2/4, 3/4 and 4/4 h chime
ST	=	VSS>VDD	Positive edge trigger for hourly chime

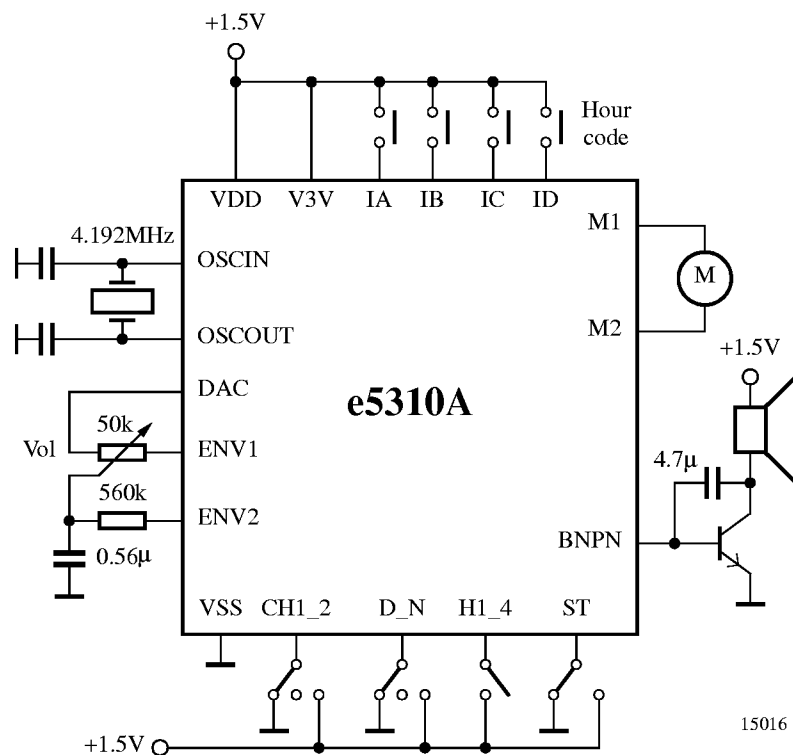


Figure 2. Class A output buffer at supply voltage of 1.5 V

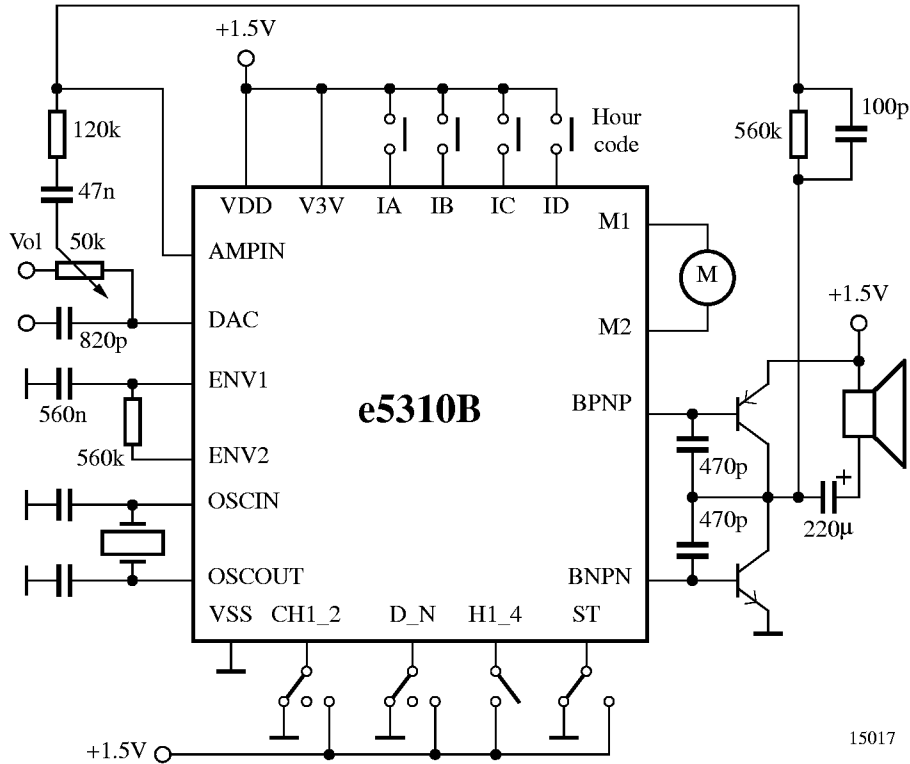


Figure 3. Class B output buffer at supply voltage of 1.5 V

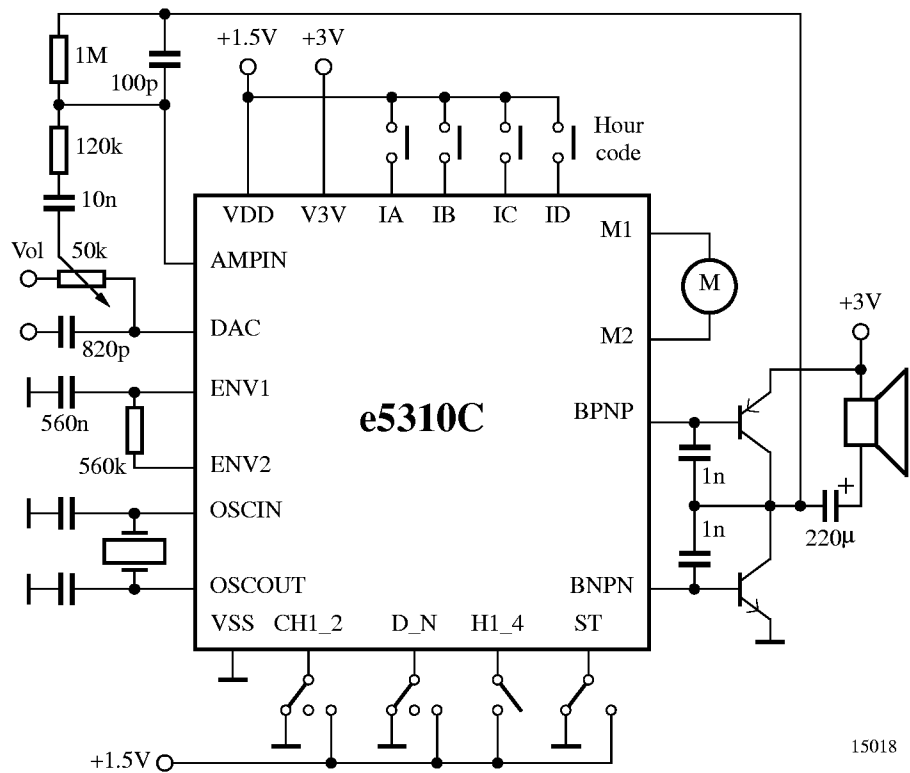
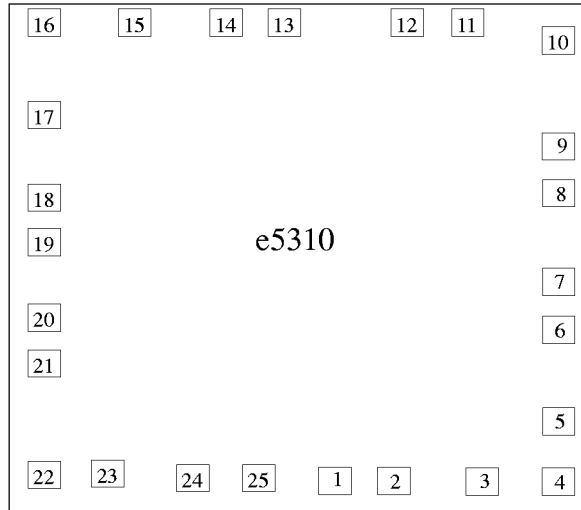


Figure 4. Class B output buffer at supply voltage of 3 V



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Pad size = 90 μm × 90 μm
Chip size = 2.33 mm × 2.22 mm = 5.17 mm²

Figure 5. Pad layout of the e5310 chip

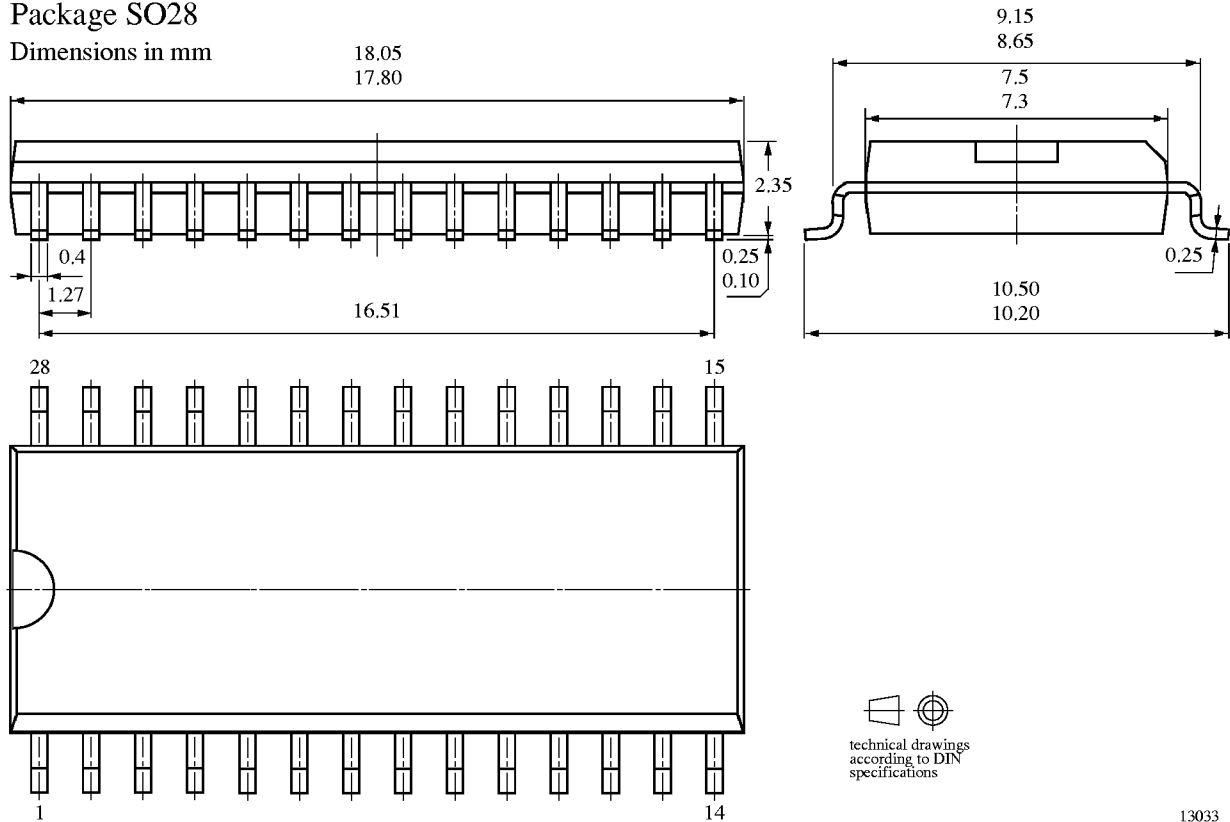
Table 3. Pad coordinates

Pad Number	Pin Name	X Position	Y Position	Pad Number	Pin Name	X Position	Y Position
1	V _{3V}	97	-986	14	ST	-180	985
2	BNPN	266	-986	15	I _A	-557	985
3	BNPN	788	-986	16	I _B	-956	985
4	V _{SS}	952	-986	17	I _C	-954	479
5	AMPIN	954	-803	18	I _D	-954	102
6	DAC	954	-426	19	T1	-954	-66
7	ENV1	954	-258	20	T2	-954	-443
8	ENV2	954	119	21	T3	-954	-611
9	OSCIN	954	287	22	T4	-954	-986
10	OSCOU	954	845	23	M2	-763	-986
11	CH1_2	602	985	24	M1	-241	-986
12	D_N	434	985	25	V _{DD}	-73	-986
13	H1_4	-12	985				

Package Information

Package SO28

Dimensions in mm



13033

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TEMIC Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany
 Telephone: 49 (0)7131 67 2594, Fax number: 49 (0)7131 67 2423